COMPLIANT



## Vishay General Semiconductor

# **Surface Mount Glass Passivated Rectifier**



DO-214AB (SMC)

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	3.0 A					
V <sub>RRM</sub>	50 V to 1000 V					
I <sub>FSM</sub>	100 A					
I <sub>R</sub> 100	10 μΑ					
V <sub>F</sub>	1.15 V					
T <sub>J</sub> max.	150 °C					

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

### **FEATURES**

- · Low profile package
- · Ideal for automated placement
- · Glass passivated chip junction
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive and telecommunication.

### **MECHANICAL DATA**

Case: DO-214AB (SMC)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)									A.C.
PARAMETER	SYMBOL	S3A	S3B	S3D	S3G	S3J	S3K	S3M	UNIT
Device marking code		SA	SB	SD	SG	SJ	SK	SM	.Va
Maximum recurrent peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	٧
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at T <sub>L</sub> = 103 °C	I <sub>F(AV)</sub>	W	Mir	ant.C	3.0	TW		WW	Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>				100				Α
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>		MM 4.	1100	55 to + 1	50		M.	°C

# Vishay General Semiconductor



ELECTRICAL CHARACTERI	STICS	6 (T <sub>A</sub> = 25 °C	unless ot	nerwis	e note	ed)	W				
PARAMETER	TEST (	CONDITIONS	SYMBOL	S3A	S3B	S3D	S3G	S3J	S3K	S3M	UNIT
Maximum instantaneous forward voltage	2.5 A	M.TW	V <sub>F</sub>	TIN.	700 r	- c0	1.15	-1			V
Maximum DC reverse current at rated DC blocking voltage	00Y.C	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	MAA	1.100	V.C	10 250				μА
Typical reverse recovery time	$I_F = 0.5$ $I_{rr} = 0.2$	A, I <sub>R</sub> = 1.0 A, 5 A	t <sub>rr</sub>	WW	W.10	00Y.C	2.5	WI			μs
Typical junction capacitance	4.0 V, 1	MHz	N C <sub>J</sub>	W	A.A.	Your	60	TT			pF

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	S3A	S3B	S3D	S3G	S3J	S3K	S3M	UNIT
Typical thermal resistance (1)	${\sf R}_{ heta \sf JA} \ {\sf R}_{ heta \sf JL}$		W	WW.	47 13	[.CO]	1.1.Y	N	°C/W

### Note:

(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0 mm) copper pad area

ORDERING INFORMATION (Example)									
PREFERRED P/N	UNIT WEIGHT (g)	REFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
S3J-E3/57T	0.211	57T	850	7" diameter plastic tape and reel					
S3J-E3/9AT	0.211	9AT	3500	13" diameter plastic tape and reel					
S3JHE3/57T (1)	0.211	57T	850	7" diameter plastic tape and reel					
S3JHE3/9AT (1)	0.211	9AT	3500	13" diameter plastic tape and reel					

### Note:

(1) Automotive grade AEC Q101 qualified

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

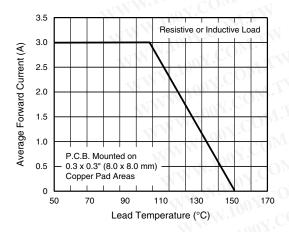


Figure 1. Forward Current Derating Curve

勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

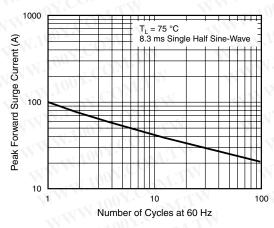


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

## Vishay General Semiconductor

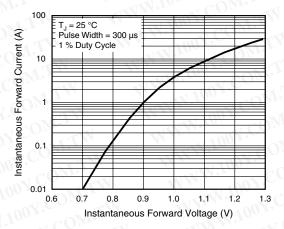


Figure 3. Typical Instantaneous Forward Characteristics

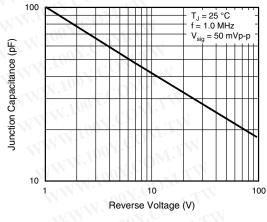


Figure 5. Typical Junction Capacitance

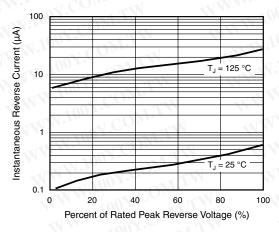


Figure 4. Typical Reverse Characteristics

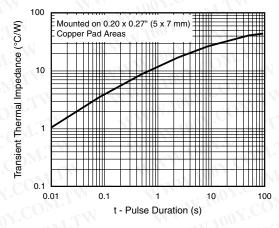
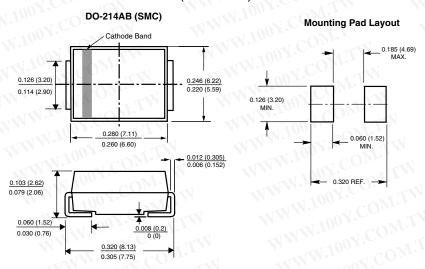


Figure 6. Typical Transient Thermal Impedance

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





Vishav

### Disclaimer

W.100Y.COM All product specifications and data are subject to change without notice.

> Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

> Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

> No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

> The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners. WWW.100Y.COM.TW

特力材料886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www. 100y. com. tw

Document Number: 91000

WWW.100Y.CON Revision: 18-Jul-08

WW.100Y.COM.TW